

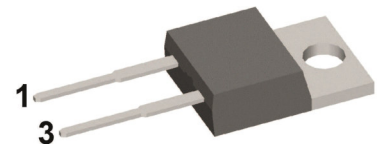
HiPerFRED

| | | |
|-----------|---|-------|
| V_{RRM} | = | 600 V |
| I_{FAV} | = | 10 A |
| t_{rr} | = | 25 ns |

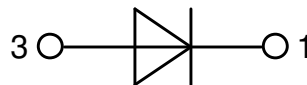
High Performance Fast Recovery Diode
 Low Loss and Soft Recovery
 Single Diode

Part number

DSEP8-06B



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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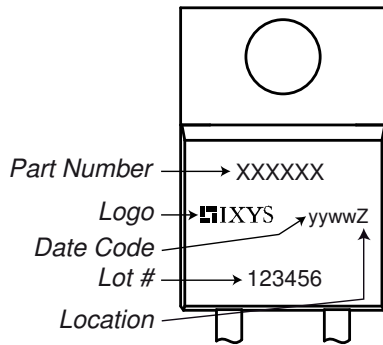


| Fast Diode | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| I_R | reverse current, drain current | $V_R = 600 V$ | $T_{VJ} = 25^{\circ}C$ | | 60 | μA | |
| | | $V_R = 600 V$ | $T_{VJ} = 150^{\circ}C$ | | 0,25 | mA | |
| V_F | forward voltage drop | $I_F = 10 A$ | $T_{VJ} = 25^{\circ}C$ | | 2,67 | V | |
| | | $I_F = 20 A$ | | | 3,19 | V | |
| | | $I_F = 10 A$ | $T_{VJ} = 150^{\circ}C$ | | 1,85 | V | |
| | | $I_F = 20 A$ | | | 2,43 | V | |
| I_{FAV} | average forward current | $T_C = 125^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 175^{\circ}C$ | | 10 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 175^{\circ}C$ | | 1,12 | V | |
| r_F | slope resistance | | | | 56 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 2,5 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0,5 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 60 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 50 | A | |
| C_J | junction capacitance | $V_R = 400V f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 6 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 10 A; V_R = 300 V$ $-di_F/dt = 200 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 1,5 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 100^{\circ}C$ | | 2,5 | A | |
| | | | $T_{VJ} = 25^{\circ}C$ | | 25 | ns | |
| | | | $T_{VJ} = 100^{\circ}C$ | | 60 | ns | |



| Package TO-220 | | | Ratings | | | |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 35 | A |
| T_{VJ} | virtual junction temperature | | -55 | | 175 | °C |
| T_{op} | operation temperature | | -55 | | 150 | °C |
| T_{stg} | storage temperature | | -55 | | 150 | °C |
| Weight | | | | 2 | | g |
| M_D | mounting torque | | 0,4 | | 0,6 | Nm |
| F_C | mounting force with clip | | 20 | | 60 | N |

Product Marking



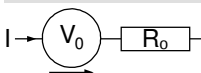
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSEP8-06B | DSEP8-06B | Tube | 50 | 496219 |

| Similar Part | Package | Voltage class |
|--------------|--------------|---------------|
| DSEP8-06A | TO-220AC (2) | 600 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}C$

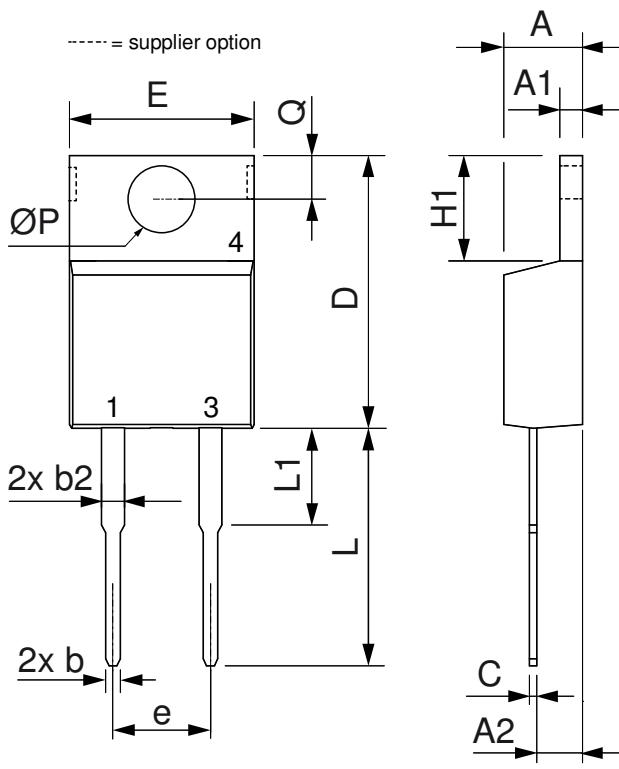


Fast Diode

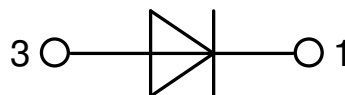
| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 1,12 | V |
| $R_{0\ max}$ | slope resistance * | 53 | mΩ |



Outlines TO-220



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.32 | 4.82 | 0.170 | 0.190 |
| A1 | 1.14 | 1.39 | 0.045 | 0.055 |
| A2 | 2.29 | 2.79 | 0.090 | 0.110 |
| b | 0.64 | 1.01 | 0.025 | 0.040 |
| b2 | 1.15 | 1.65 | 0.045 | 0.065 |
| C | 0.35 | 0.56 | 0.014 | 0.022 |
| D | 14.73 | 16.00 | 0.580 | 0.630 |
| E | 9.91 | 10.66 | 0.390 | 0.420 |
| e | 5.08 | BSC | 0.200 | BSC |
| H1 | 5.85 | 6.85 | 0.230 | 0.270 |
| L | 12.70 | 13.97 | 0.500 | 0.550 |
| L1 | 2.79 | 5.84 | 0.110 | 0.230 |
| ØP | 3.54 | 4.08 | 0.139 | 0.161 |
| Q | 2.54 | 3.18 | 0.100 | 0.125 |



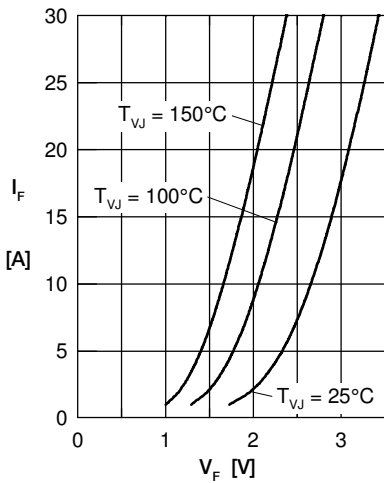
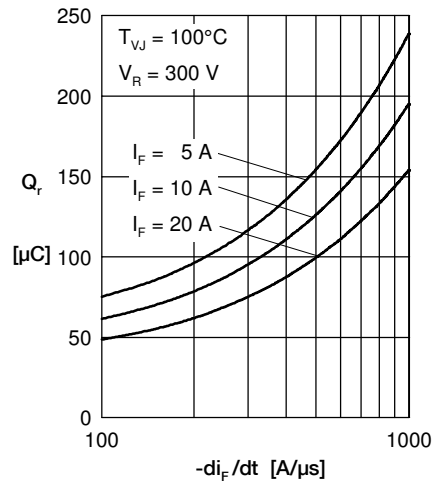
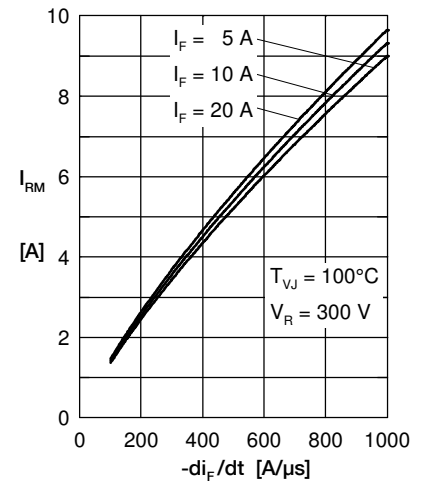
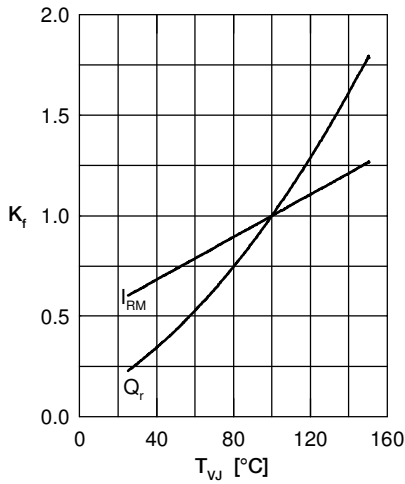
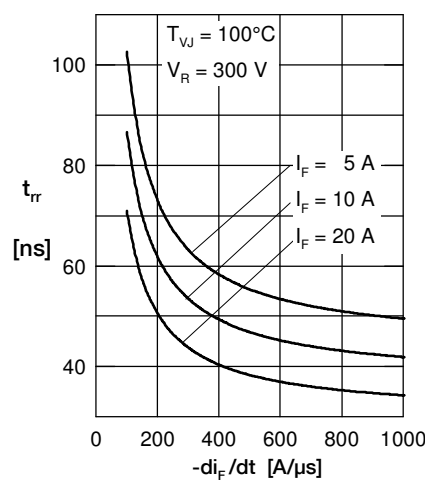
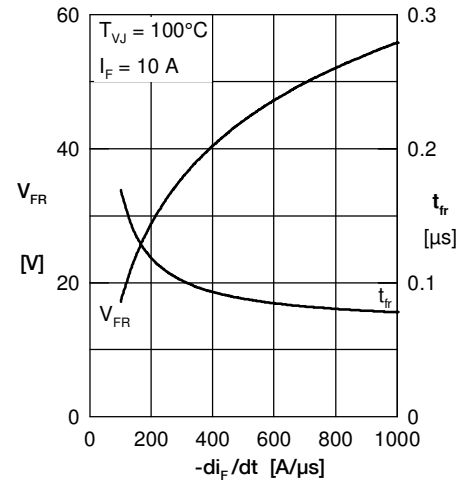
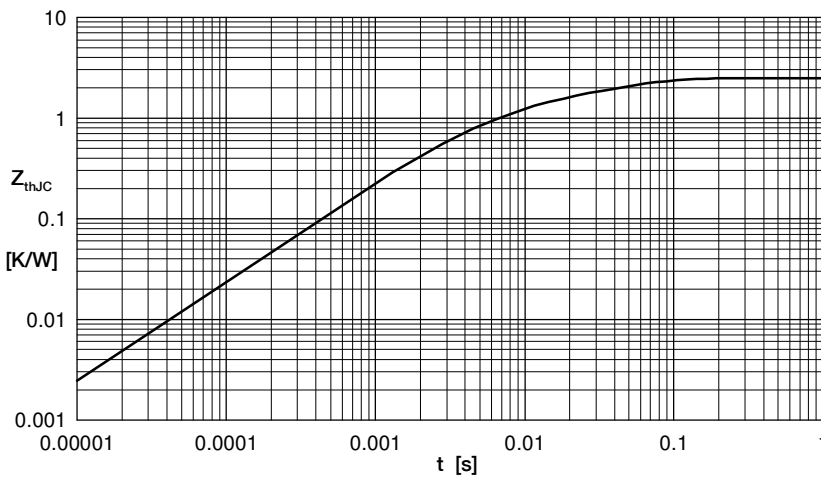
Fast Diode

 Fig. 1 Forward current I_F versus V_F

 Fig. 2 Typ. reverse recov. charge Q_r versus $-di_F/dt$

 Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

 Fig. 4 Typ. dynamic parameters Q_r, I_{RM} versus T_{VJ}

 Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

 Fig. 6 Typ. peak forward voltage V_{FR} and t_{rr} versus di_F/dt


Fig. 7 Transient thermal impedance junction to case

 Constants for Z_{thJC} calculation:

| i | R_{thi} [K/W] | t_i [s] |
|---|-----------------|-----------|
| 1 | 1.449 | 0.0052 |
| 2 | 0.5578 | 0.0003 |
| 3 | 0.4931 | 0.0169 |